Quad 2-Input NOR Gate

- Outputs Source/Sink 24 mA
- 'ACT02 Has TTL Compatible Inputs

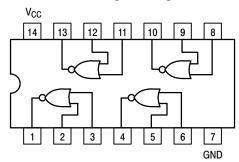


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)

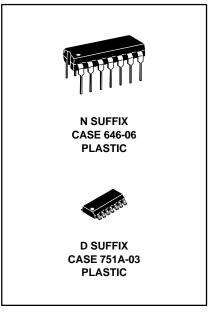
MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
V _{out}	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
I _{in}	DC Input Current, per Pin	±20	mA
l _{out}	DC Output Sink/Source Current, per Pin	±50	mA
I _{CC}	DC V _{CC} or GND Current per Output Pin	±50	mA
T _{stg}	Storage Temperature	-65 to +150	°C

^{*} Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

MC74AC02 MC74ACT02

QUAD 2-INPUT NOR GATE



RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
.,	Cumple Maltage	'AC	2.0	5.0	6.0	,,
V _{CC}	Supply Voltage	'ACT	4.5	5.0	5.5	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Ref. to GND)		0		V _{CC}	V
		V _{CC} @ 3.0 V		150		
Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V		40		ns/V	
	To Devides except estimating and	V _{CC} @ 5.5 V		25		
	Input Rise and Fall Time (Note 2)	V _{CC} @ 4.5 V		10		0./
t _r , t _f	'ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V		8.0		ns/V
TJ	Junction Temperature (PDIP)				140	°C
T _A	Operating Ambient Temperature Range		-40	25	85	°C
I _{OH}	Output Current — High				-24	mA
I _{OL}	Output Current — Low				24	mA

^{1.} V_{in} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times.

^{2.} V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

	Parameter		74AC T _A = +25°C		74AC	Unit		
Symbol		V _{CC} (V)			T _A = -40°C to +85°C		Conditions	
			Тур	Guar	anteed Limits			
V _{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V_{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V _{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I _{OUT} = -50 μA	
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	V	*V _{IN} = V _{IL} or V _{IH} -12 mA I _{OH} -24 mA -24 mA	
V _{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	Ι _{ΟUT} = 50 μΑ	
		3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	V	$^{*}V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA I_{OL} 24 mA 24 mA	
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μΑ	V _I = V _{CC} , GND	
I _{OLD}	†Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65 V Max	
I _{OHD}	Output Current	5.5			-75	mA	V _{OHD} = 3.85 V Min	
Icc	Maximum Quiescent Supply Current	5.5		4.0	40	μΑ	V _{IN} = V _{CC} or GND	

^{*} All outputs loaded; thresholds on input associated with output under test.

Note: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC} .

AC CHARACTERISTICS (For Figures and Waveforms — See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

		V _{CC} *	Т	74AC _A = +25°	С	T _A = -	AC -40°C		Fig.
Symbol	Parameter	(V)			to +85°C C _L = 50 pF		Unit	No.	
			Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay	3.3 5.0	1.5 1.5	5.0 4.0	7.5 6.0	1.0 1.0	8.0 6.5	ns	3-5
t _{PHL}	Propagation Delay	3.3 5.0	1.5 1.5	5.0 4.5	7.5 6.5	1.0 1.0	8.0 7.0	ns	3-5

 $^{^*}$ Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

[†]Maximum test duration 2.0 ms, one output loaded at a time.

DC CHARACTERISTICS

	Parameter		74ACT T _A = +25°C		74ACT	Unit		
Symbol		V _{CC} (V)			T _A = -40°C to +85°C		Conditions	
			Тур	Guar	anteed Limits			
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I _{OUT} = -50 μA	
		4.5 5.5		3.86 4.86	3.76 4.76	V	* V _{IN} = V _{IL} or V _{IH} $^-$ 24 mA $^-$ 10H $^-$ 24 mA	
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 μA	
		4.5 5.5		0.36 0.36	0.44 0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA	
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μΑ	V _I = V _{CC} , GND	
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6		1.5	mA	$V_{I} = V_{CC} - 2.1 \text{ V}$	
I _{OLD}	†Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65 V Max	
I _{OHD}	Output Current	5.5			-75	mA	V _{OHD} = 3.85 V Min	
I _{CC}	Maximum Quiescent Supply Current	5.5		4.0	40	μΑ	V _{IN} = V _{CC} or GND	

 $^{^{\}star}$ All outputs loaded; thresholds on input associated with output under test.

AC CHARACTERISTICS (For Figures and Waveforms — See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

			74ACT			74ACT			Fig. No.
Symbol	Parameter	V _{CC} * (V)					Unit		
			Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay	5.0	1.5		8.5	1.0	9.0	ns	3-6
t _{PHL}	Propagation Delay	5.0	1.5		9.5	1.0	10	ns	3-6

^{*} Voltage Range 5.0 V is 5.0 V ± 0.5 V.

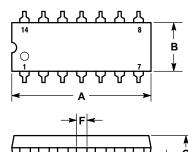
CAPACITANCE

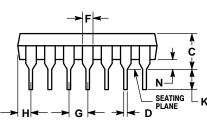
Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	30	pF	V _{CC} = 5.0 V

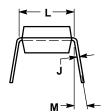
[†]Maximum test duration 2.0 ms, one output loaded at a time.

OUTLINE DIMENSIONS

N SUFFIX PLASTIC DIP PACKAGE CASE 646–06 ISSUE L







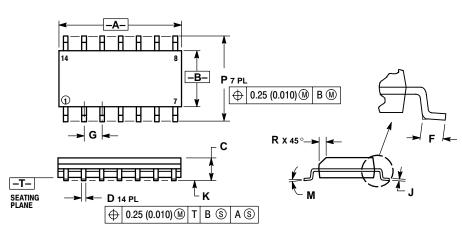
- NOTES:
 1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
 2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 3. DIMENSION B DOES NOT INCLUDE MOLD ELACH.
- FLASH.
 4. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.300 BSC		7.62	BSC	
M	0°	10°	0°	10°	
N	0.015	0.039	0.39	1.01	

OUTLINE DIMENSIONS

D SUFFIX

PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F



NOTES:

- NOTES:

 1. DIMEN SIONING AND TOLERANCING PER ANSI 714.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INCHES					
DIM	MIN	MAX	MIN	MAX				
Α	8.55	8.75	0.337	0.344				
В	3.80	4.00	0.150	0.157				
С	1.35	1.75	0.054	0.068				
D	0.35	0.49	0.014	0.019				
F	0.40	1.25	0.016	0.049				
G	1.27	BSC	0.050 BSC					
J	0.19	0.25	0.008	0.009				
K	0.10	0.25	0.004	0.009				
М	0 °	7°	0 °	7°				
P	5.80	6.20	0.228	0.244				
R	0.25	0.50	0.010	0.019				





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